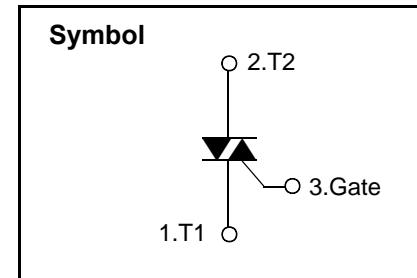


Bi-Directional Triode Thyristor

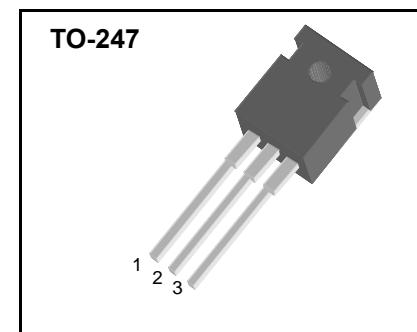
Features

- ◆ Repetitive Peak Off-State Voltage : 600V
- ◆ R.M.S On-State Current ($I_{T(RMS)} = 25 \text{ A}$)
- ◆ High Commutation dv/dt



General Description

This device is suitable for AC switching application, phase control application such as fan speed and temperature modulation control, lighting control and static switching relay.



Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Condition	Ratings	Units
V_{DRM}	Repetitive Peak Off-State Voltage		600	V
$I_{T(RMS)}$	R.M.S On-State Current	$T_C = 86^\circ\text{C}$	25	A
I_{TSM}	Surge On-State Current	One Cycle, 50Hz/60Hz, Peak, Non-Repetitive	225/250	A
I^2t	I^2t		260	A^2s
P_{GM}	Peak Gate Power Dissipation		5.0	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.5	W
I_{GM}	Peak Gate Current		2.0	A
V_{GM}	Peak Gate Voltage		10	V
T_J	Operating Junction Temperature		- 40 ~ 125	$^\circ\text{C}$
T_{STG}	Storage Temperature		- 40 ~ 150	$^\circ\text{C}$
	Mass		6.2	g

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Electrical Characteristics

Symbol	Items	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
I_{DRM}	Repetitive Peak Off-State Current	$V_D = V_{DRM}$, Single Phase, Half Wave $T_J = 125^\circ C$	—	—	5.0	mA
V_{TM}	Peak On-State Voltage	$I_T = 35 A$, Inst. Measurement	—	—	1.4	V
I^+_{GT1}	I	Gate Trigger Current	—	—	30	mA
I^-_{GT1}	II		—	—	30	
I^-_{GT3}	III		—	—	30	
V^+_{GT1}	I	Gate Trigger Voltage	—	—	1.5	V
V^-_{GT1}	II		—	—	1.5	
V^-_{GT3}	III		—	—	1.5	
V_{GD}	Non-Trigger Gate Voltage	$T_J = 125^\circ C$, $V_D = 1/2 V_{DRM}$	0.2	—	—	V
$(dv/dt)_c$	Critical Rate of Rise Off-State Voltage at Commutation	$T_J = 125^\circ C$, $[di/dt]_c = -12.5 A/ms$, $V_D=2/3 V_{DRM}$	6	—	—	V/ μ s
I_H	Holding Current		—	35	—	mA
$R_{th(j-c)}$	Thermal Impedance	Junction to case	—	—	1.3	°C/W

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Fig 1. Gate Characteristics

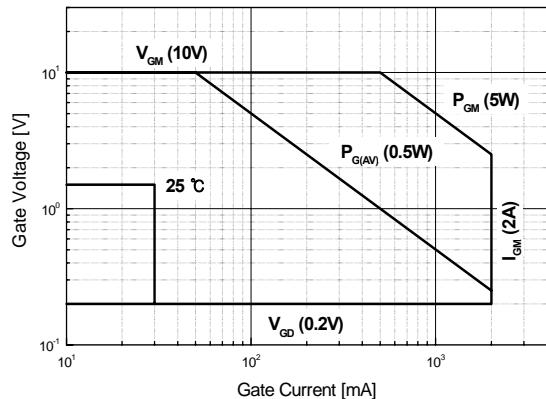
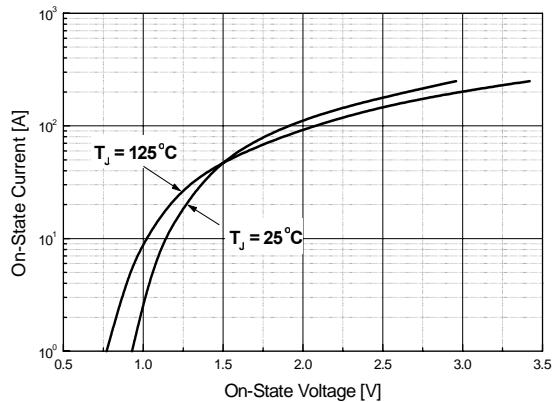
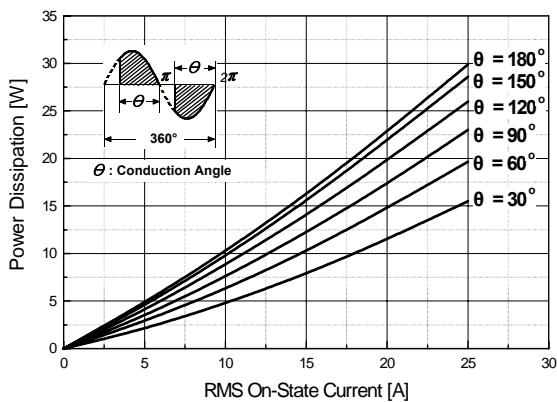


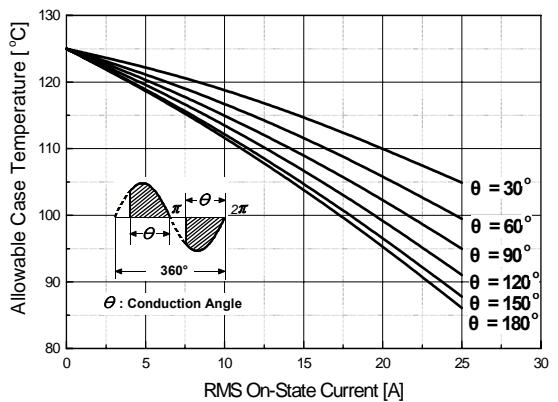
Fig 2. On-State Voltage



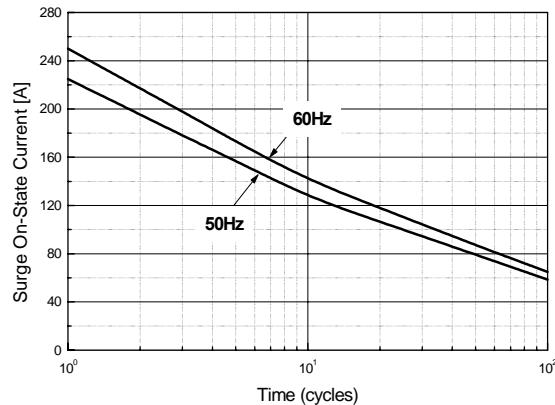
**Fig 3. On State Current vs.
Maximum Power Dissipation**



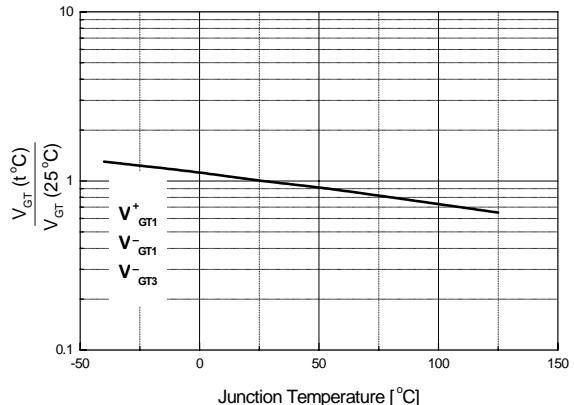
**Fig 4. On State Current vs.
Allowable Case Temperature**



**Fig 5. Surge On-State Current Rating
(Non-Repetitive)**



**Fig 6. Gate Trigger Voltage vs.
Junction Temperature**



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Fig 7. Gate Trigger Current vs. Junction Temperature

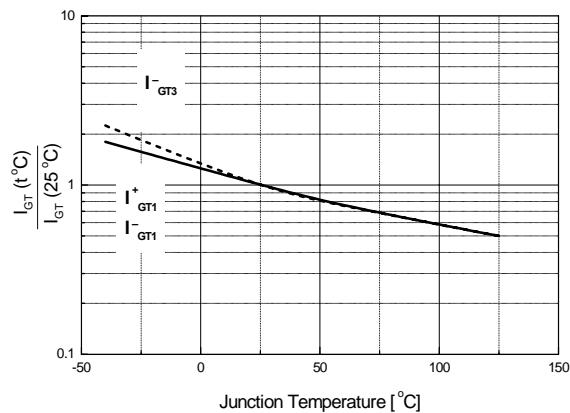


Fig 8. Transient Thermal Impedance

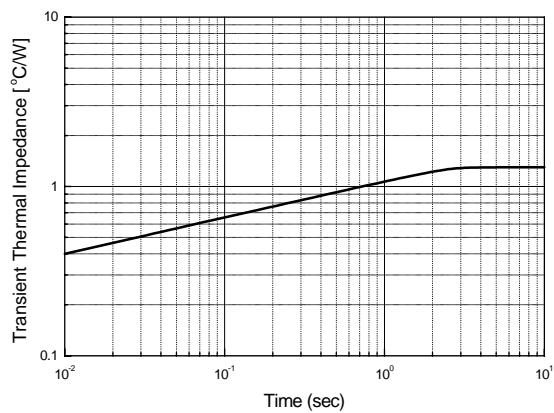
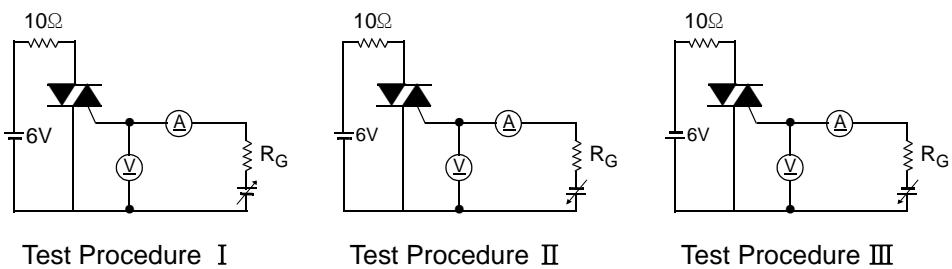


Fig 9. Gate Trigger Characteristics Test Circuit



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TO-247 Package Dimension

Dim.	mm			Inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.77		16.03	0.621		0.631
B	20.80		21.10	0.819		0.831
C	20.05		20.31	0.789		0.800
D	4.48		4.58	0.176		0.180
E	4.27		4.37	0.168		0.172
F	5.32		5.58	0.209		0.220
G	4.90		5.16	0.193		0.203
H	1.90		2.06	0.075		0.081
I	2.35		2.45	0.093		0.096
J		0.6			0.024	
K	1.93		2.13	0.076		0.084
L	1.07		1.33	0.042		0.052
M	2.99		3.25	0.118		0.128
ϕ	3.56		3.66	0.140		0.144

